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PATENT & TRADEMARK OFFICE

PATENT
Customer No. 22,852
Attorney Docket No. 04329.2306

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of:)
)
Yoshio OZAWA, et al.) Group Art Unit: 2826
)
Serial No.: 09/559,757) Examiner: Mondt, Johannes P.
)
Filed: April 27, 2000)
)
For: SEMICONDUCTOR DEVICE AND)
METHOD OF MANUFACTURE)
THEREOF)

Assistant Commissioner for Patents
Washington, DC 20231

Sir:

AMENDMENT

In response to the Office Action of June 19, 2002, with a period for response extending through September 19, 2002, please amend the application as follows:

IN THE CLAIMS:

✓
Please cancel claim 4 without prejudice or disclaimer of the subject matter therein, and amend claim 1 as follows:

C1
1. (Three Times Amended) A semiconductor device comprising:
a semiconductor substrate having a main plane in which a channel of a transistor is formed, the semiconductor substrate comprising a first region and a second region defined in a section taken along a direction of a channel length, the second region having a surface located lower than that of the first region, and the second region being connected to the first region;

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